7 GHz to 34 GHz, MMIC, Double Balanced Mixer

Data Sheet **HMC774ALC3B**

FEATURES

Passive: no dc bias required
Input IP3: 20 dBm typical, downconverter
LO to RF isolation: 30 dB typical
Wide IF bandwidth: dc to 8 GHz
12-terminal, ceramic, 2.90 mm × 2.90 mm LCC

APPLICATIONS

Point to point radios
Point to multipoint radios and very small aperture terminals (VSATs)
Test equipment and sensors
Military end use

FUNCTIONAL BLOCK DIAGRAM

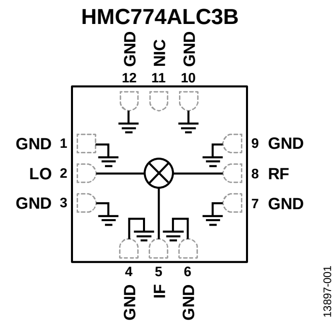

Figure 1.

GENERAL DESCRIPTION

The HMC774ALC3B is a general-purpose, double balanced mixer in a leadless, RoHS compliant, surface-mount package that can be used as an upconverter or a downconverter between 7 GHz and 34 GHz. This mixer requires no external components or matching circuitry. The HMC774ALC3B provides excellent LO to RF isolation and LO to IF isolation due to optimized balun structures.

The mixer operates best with a LO drive level of 15 dBm (typical). The HMC774ALC3B eliminates the need for wire bonding, allowing the use of surface-mount manufacturing techniques.

Rev. A **Document Feedback**

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6/2018—Rev. 0 to Rev. A

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2/2018—Revision 0: Initial Version

SPECIFICATIONS

7 GHz TO 20 GHz FREQUENCY RANGE

Measurements are performed in downconverter mode at T_A = 25°C, IF frequency (f_{IF}) = 500 MHz, RF power (P_{RF}) = −10 dBm, LO power (P_{LO}) = +15 dBm, and upper sideband (USB) with 50 Ω system, unless otherwise noted.

Table 1.

Parameter	Symbol	Min	Typ	Max	Unit
FREQUENCY RANGE					
Radio Frequency	f_{RF}	7		20	GHz
Intermediate Frequency	f_{IF}	DC		8	GHz
Local Oscillator	f_{LO}	7		34	GHz
LO DRIVE LEVEL		11	15	17	dBm
RF PERFORMANCE					
Downconverter					
Conversion Loss			10	15	dB
Input Third-Order Intercept	IP3	12.5	20		dBm
Input Second-Order Intercept	IP2		48		dBm
Input 1 dB Compression Point	P1dB		12		dB
Single Sideband Noise Figure	SSB NF		12		dB
Isolation					
RF to IF		7	9		dB
LO to RF		28	30		dB
LO to IF		20.5	23		dB
Upconverter					
Conversion Loss			10		dB
Input Third-Order Intercept	IP3		27		dBm

20 GHz TO 34 GHz FREQUENCY RANGE

Measurements are performed in downconverter mode at T_A = 25°C, f_{IF} = 500 MHz, P_{RF} = −10 dBm, P_{LO} = +15 dBm, and lower sideband with 50 Ω system, unless otherwise noted.

Table 2.

Parameter	Symbol	Min	Typ	Max	Unit
FREQUENCY RANGE					
Radio Frequency	f_{RF}	20		34	GHz
Intermediate Frequency	f_{IF}	DC		8	GHz
Local Oscillator	f_{LO}	20		34	GHz
LO DRIVE LEVEL		11	15	17	dBm
RF PERFORMANCE					
Downconverter					
Conversion Loss			12	15.5	dB
Input Third-Order Intercept	IP3	17	20		dBm
Input Second-Order Intercept	IP2		40		dBm
Input 1 dB Compression Point	P1dB		13		dB
Single Sideband Noise Figure	SSB NF		12		dB
Isolation					
RF to IF		25	30		dB
LO to RF		27.5	33		dB
LO to IF		30	40		dB
Upconverter					
Conversion Loss			9		dB
Input Third-Order Intercept	IP3		23		dBm

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
RF Input Power when LO = 18 dBm	21 dBm
LO Drive	25 dBm
IF Input Power when LO = 18 dBm	21 dBm
LO and RF DC Source and Sink Current	55 mA
IF Port Maximum Sink and Source Current	3 mA
Maximum Channel Temperature	175°C
Maximum Junction Temperature	165°C
Continuous Power Dissipation, P_{DISS} (T_A = 85°C, Derate 2.9 mW/°C Above 85°C)	189 mW
Operating Temperature Range	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature Range	−65°C to +150°C
Reflow Temperature	260°C
Electrostatic Discharge (ESD) Sensitivity	
Human Body Model (HBM)	Class 1C (1.5 kV)
Field Induced Charge Device Model (FICDM)	Class IV (1.25 kV)

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

θ_{JA} is the thermal resistance value that is measured from junction to air, and θ_{JC} is the thermal resistance value that is measured from junction to case (package).

Table 4. Thermal Resistance

Package Type[1]	θ_{JA}	θ_{JC}	Unit
E-12-4	120	274	°C/W

[1] See JEDEC standard JESD51-2 for additional information on optimizing the thermal impedance (PCB with 3 × 3 vias).

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

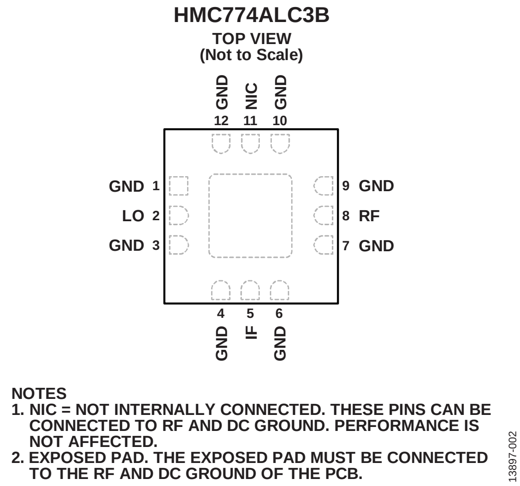

Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 3, 4, 6, 7, 9, 10, 12	GND	Ground. These pins must be connected to the RF and dc ground of the PCB. See Figure 3 for the interface schematic.
2	LO	Local Oscillator Port. This pin is dc-coupled and matched to 50 Ω. For the maximum dc current capability of this pin, see the Absolute Maximum Ratings section. See Figure 4 for the interface schematic.
5	IF	Intermediate Frequency Port. For applications not requiring operation to dc, dc block this port externally using a series capacitor of a value chosen to pass the necessary IF frequency range. For operation to dc, this pin must not source or sink more than 3 mA of current or die malfunction and possible die failure can result. See Figure 5 for the interface schematic.
8	RF	Radio Frequency Port. This pin is dc-coupled and matched to 50 Ω. For the maximum dc current capability of this pin, see the Absolute Maximum Ratings section. See Figure 6 for the interface schematic.
11	NIC	Not Internally Connected. These pins can be connected to RF and dc ground. Performance is not affected.
	EPAD	Exposed Pad. The exposed pad must be connected to the RF and dc ground of the PCB.

INTERFACE SCHEMATICS

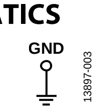

Figure 3. GND Interface Schematic

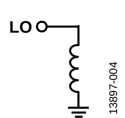

Figure 4. LO Interface Schematic

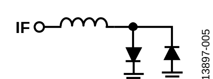

Figure 5. IF Interface Schematic

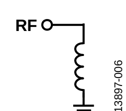

Figure 6. RF Interface Schematic

TYPICAL PERFORMANCE CHARACTERISTICS

DOWNCONVERTER, IF = 500 MHz, UPPER SIDEBAND

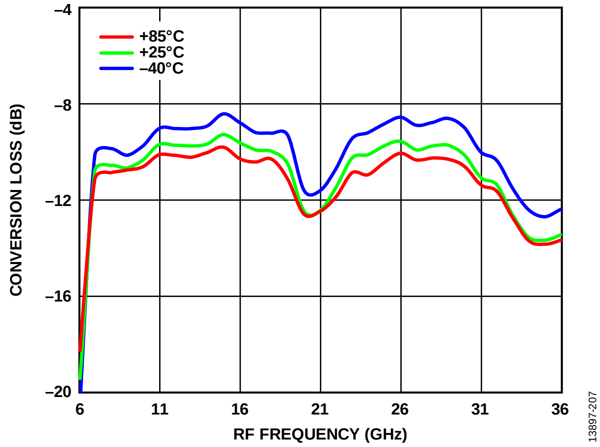

Figure 7. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

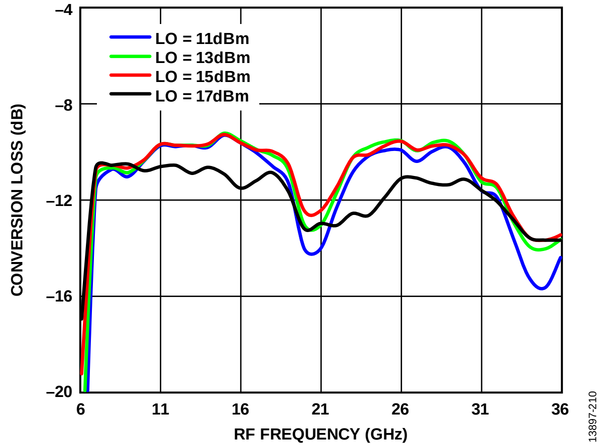

Figure 10. Conversion Loss vs. RF Frequency over LO Drives

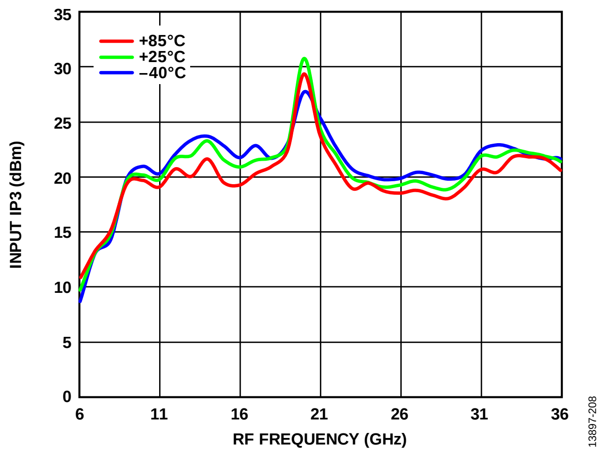

Figure 8. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

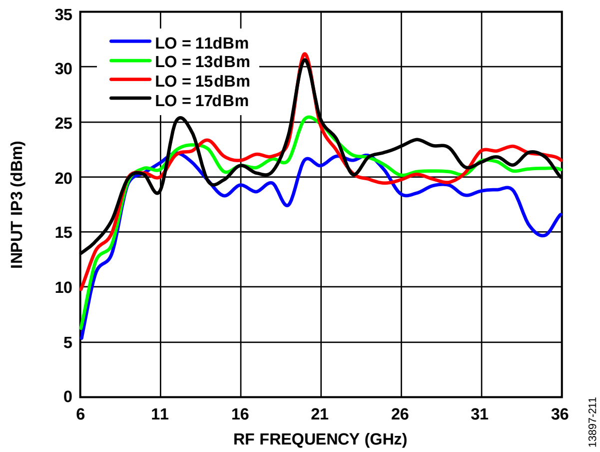

Figure 11. Input IP3 vs RF Frequency over Various LO Drives

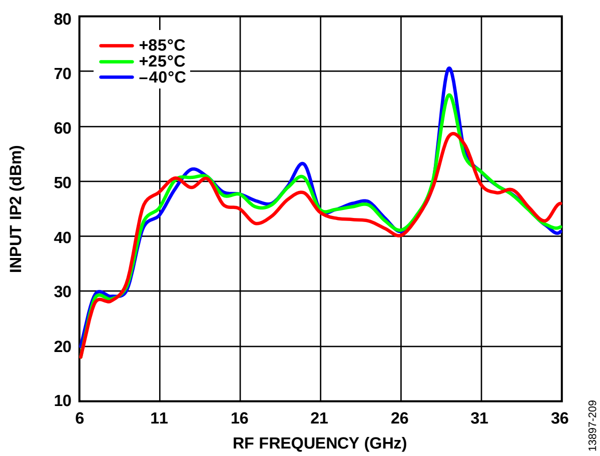

Figure 9. Input IP2 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

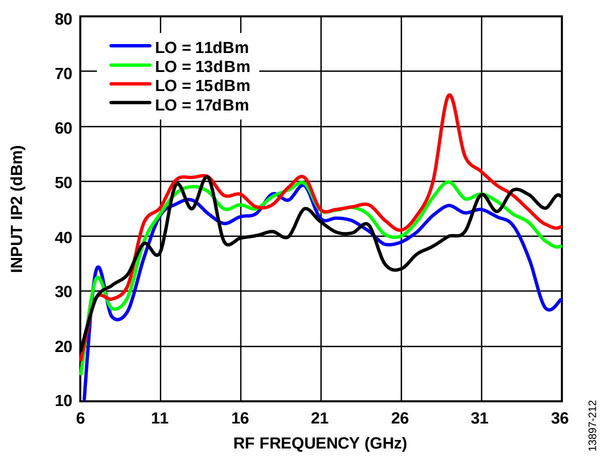

Figure 12. Input IP2 vs. RF Frequency over Various LO Drives

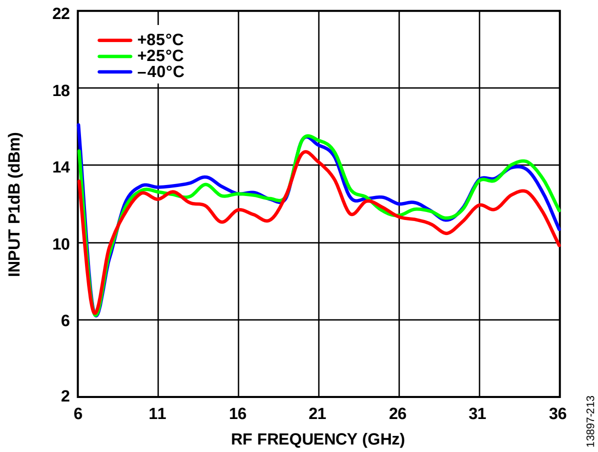

Figure 13. Input P1dB vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

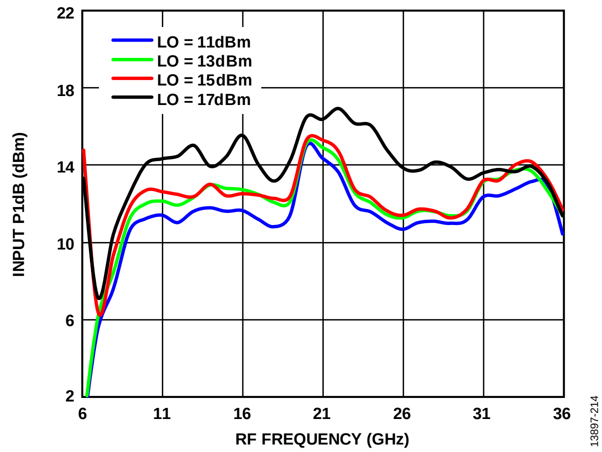

Figure 14. Input P1dB vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 500 MHz, LOWER SIDEBAND

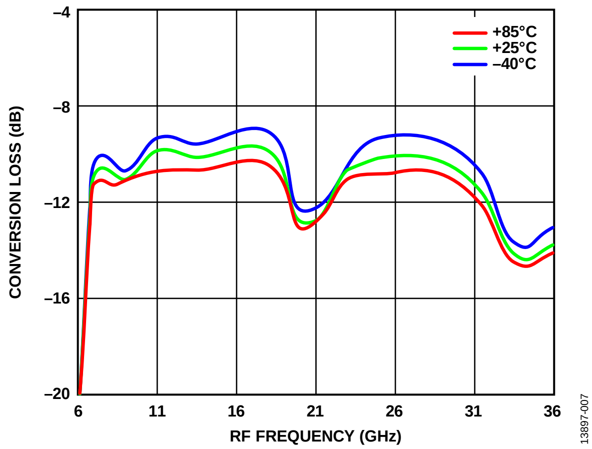

Figure 15. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

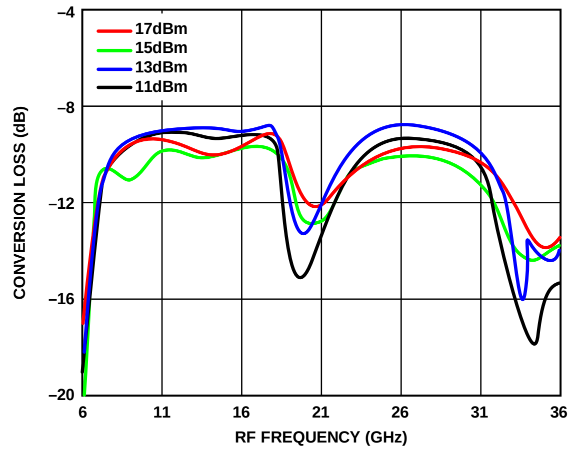

Figure 18. Conversion Loss vs. RF Frequency over LO Drives

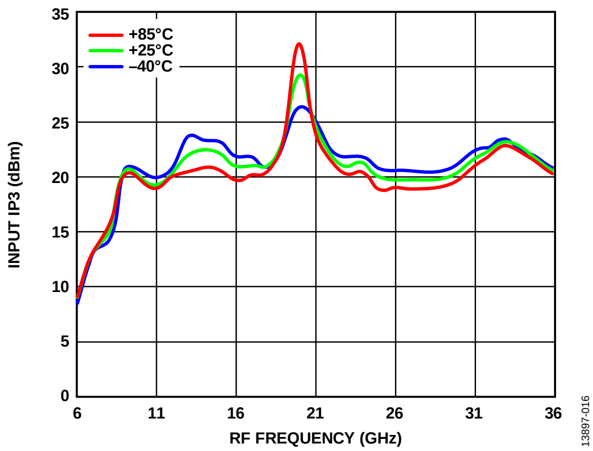

Figure 16. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

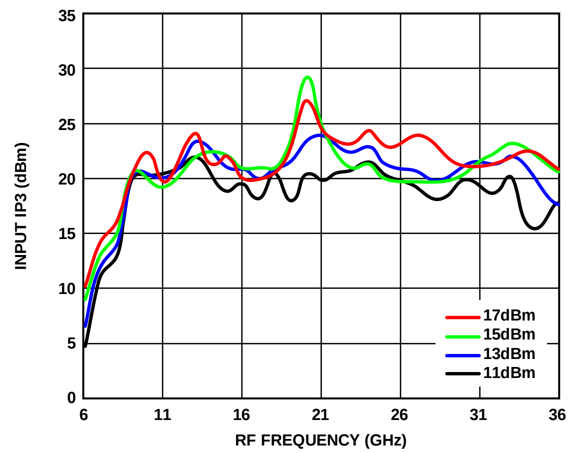

Figure 19. Input IP3 vs. RF Frequency over Various LO Drives

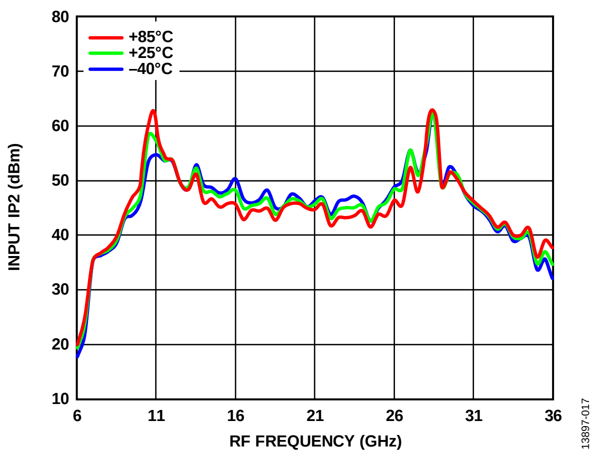

Figure 17. Input IP2 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

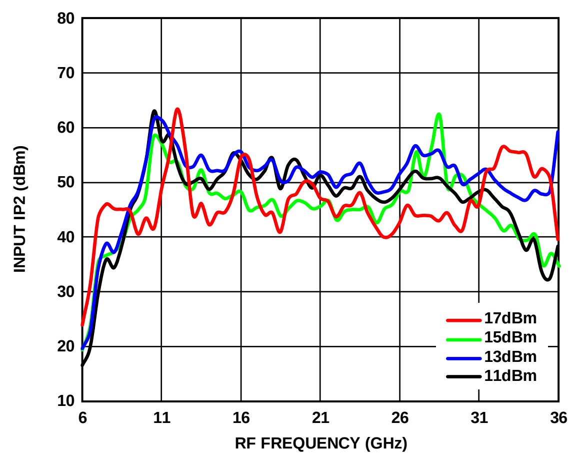

Figure 20. Input IP2 vs. RF Frequency over Various LO Drives

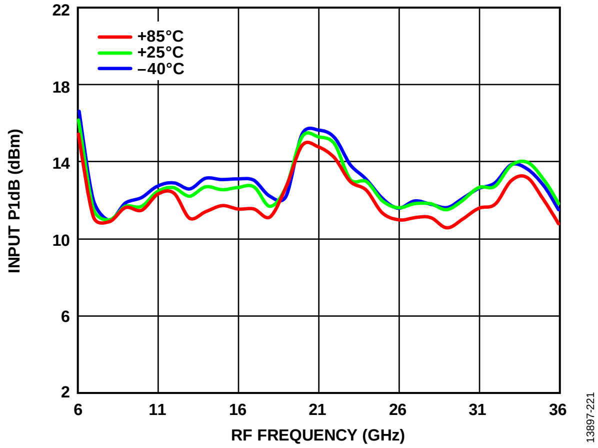

Figure 21. Input P1dB vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

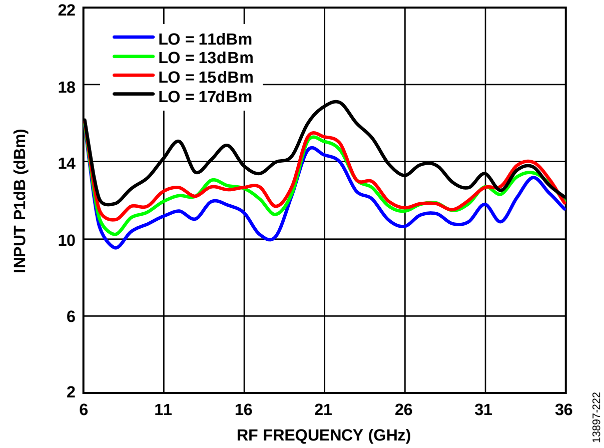

Figure 22. Input P1dB vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 3000 MHz, UPPER SIDEBAND

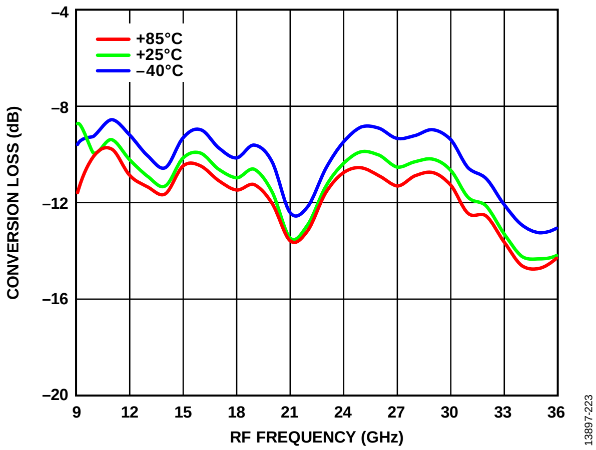

Figure 23. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

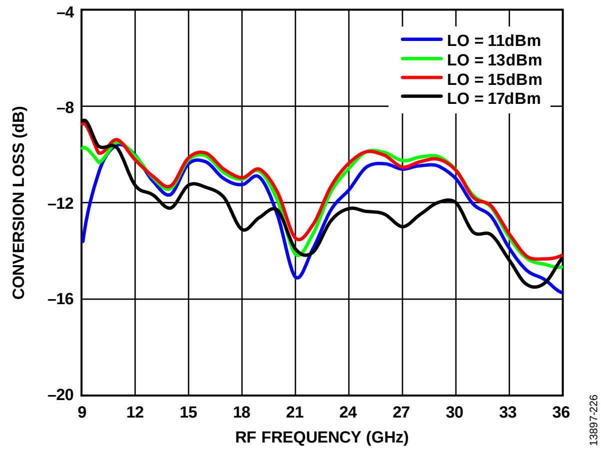

Figure 26. Conversion Loss vs. RF Frequency over Various LO Drives

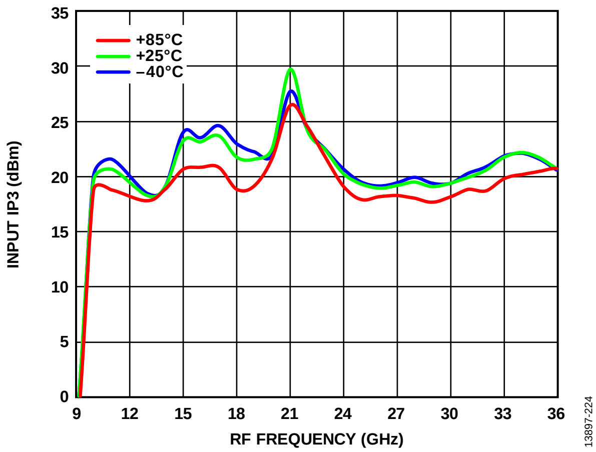

Figure 24. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

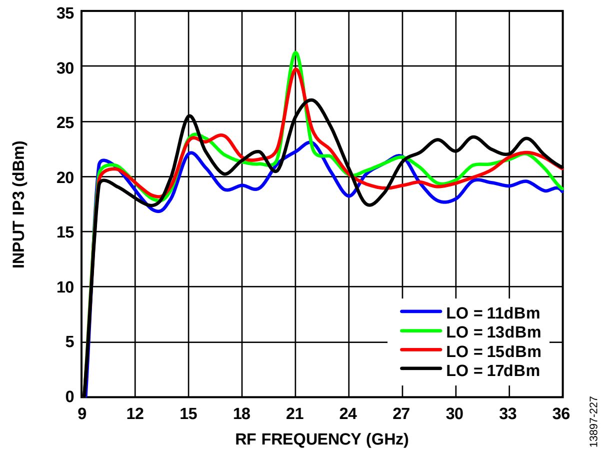

Figure 27. Input IP3 vs. RF Frequency over Various LO Drives

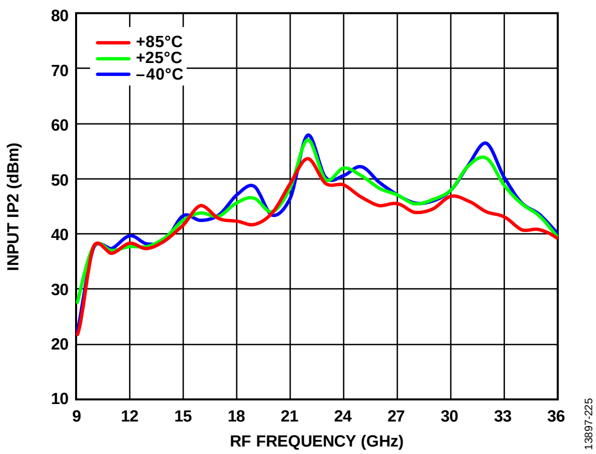

Figure 25. Input IP2 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

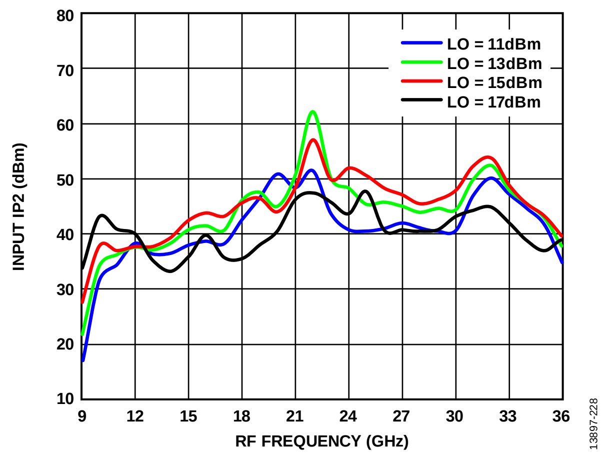

Figure 28. Input IP2 vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 3000 MHz, LOWER SIDEBAND

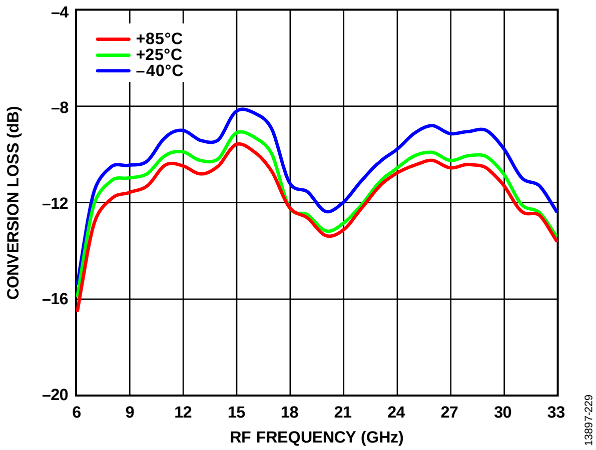

Figure 29. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

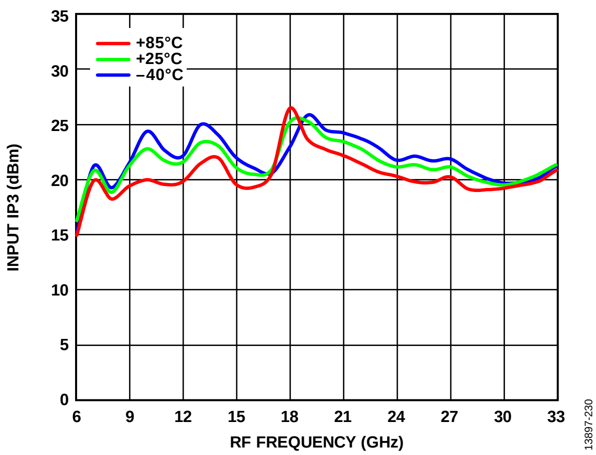

Figure 30. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

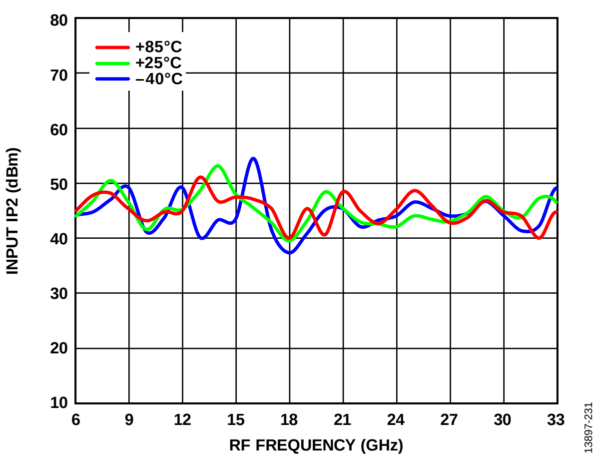

Figure 31. Input IP2 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

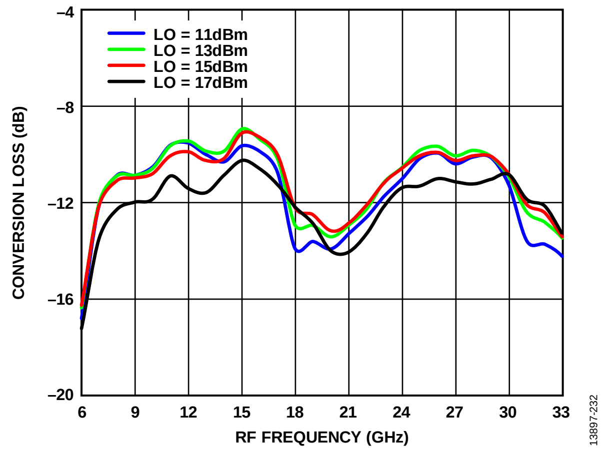

Figure 32. Conversion Loss vs. RF Frequency over Various LO Drives

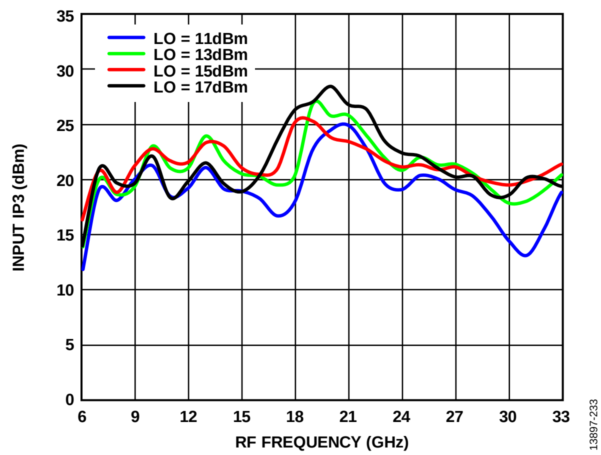

Figure 33. Input IP3 vs. RF Frequency over Various LO Drives

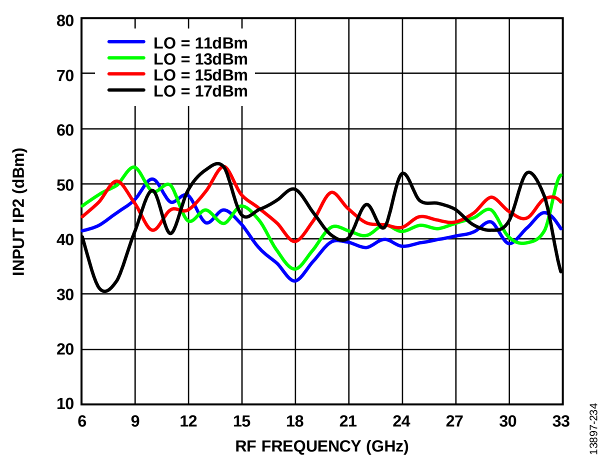

Figure 34. Input IP2 vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 8000 MHz, UPPER SIDEBAND

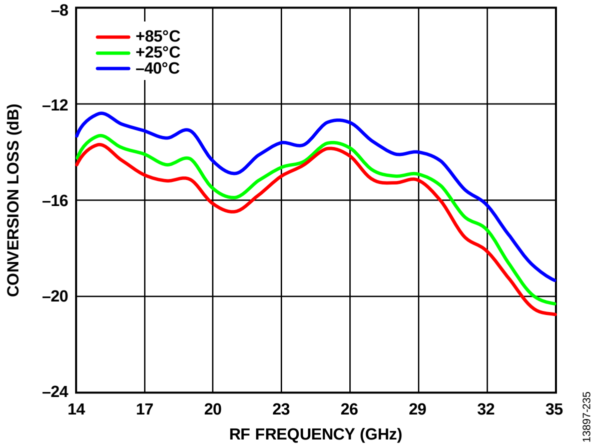

Figure 35. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

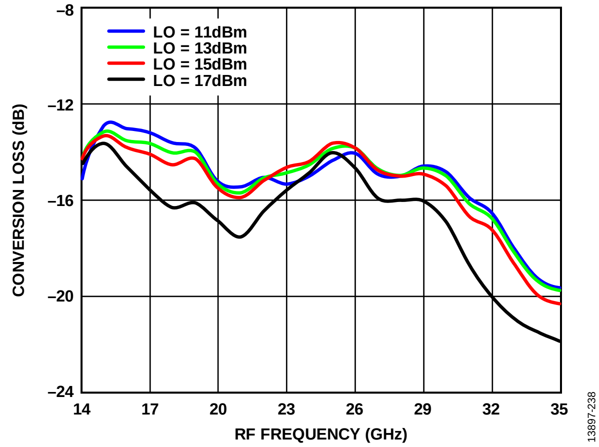

Figure 38. Conversion Loss vs. RF Frequency over Various LO Drives

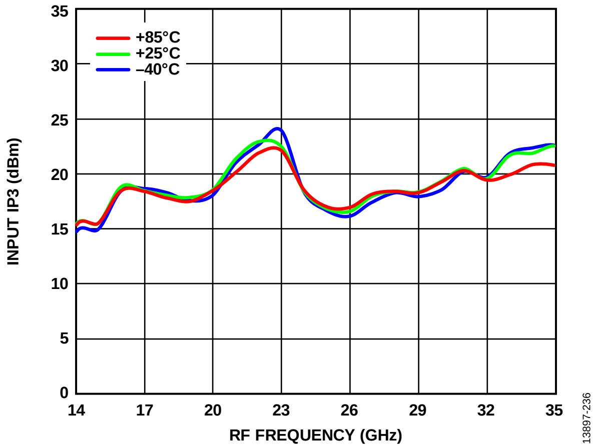

Figure 36. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

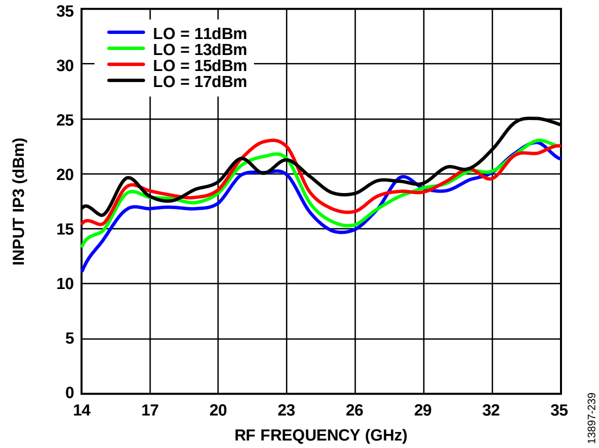

Figure 39. Input IP3 vs. RF Frequency over Various LO Drives

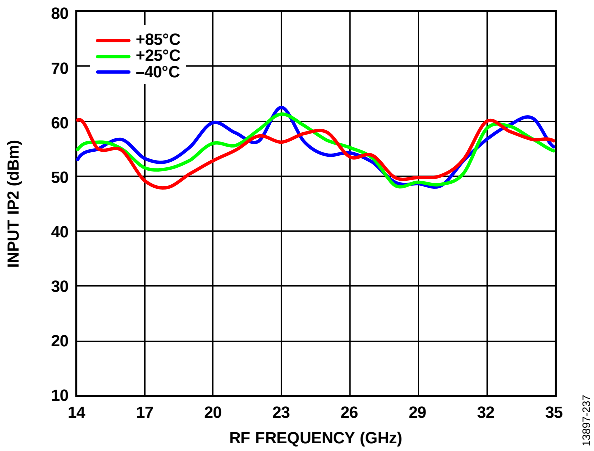

Figure 37. Input IP2 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

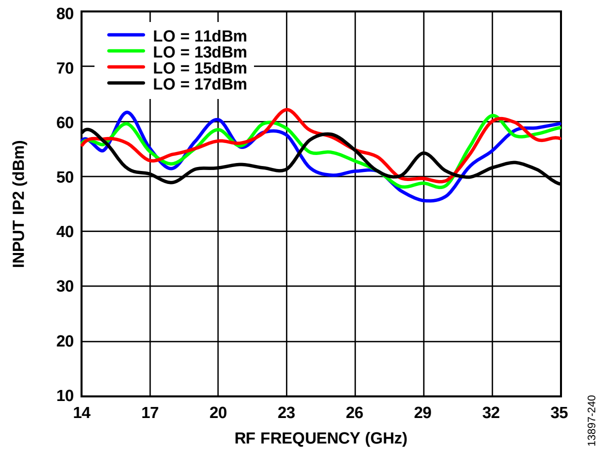

Figure 40. Input IP2 vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 8000 MHz, LOWER SIDEBAND

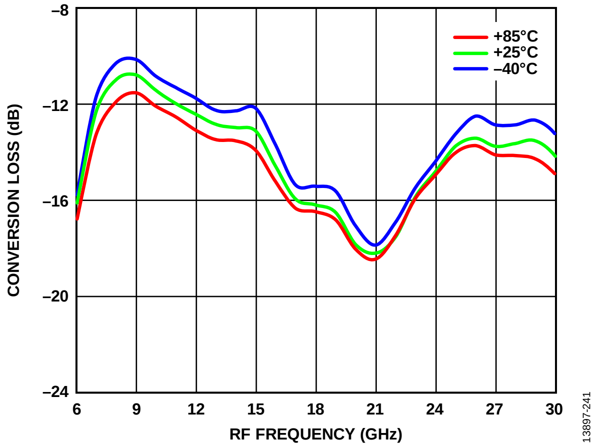

Figure 41. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

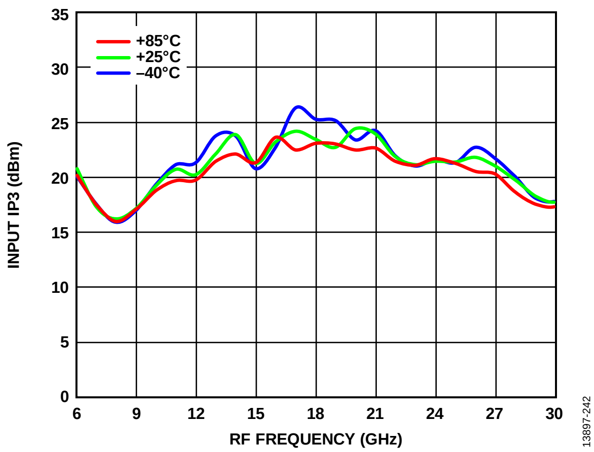

Figure 42. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

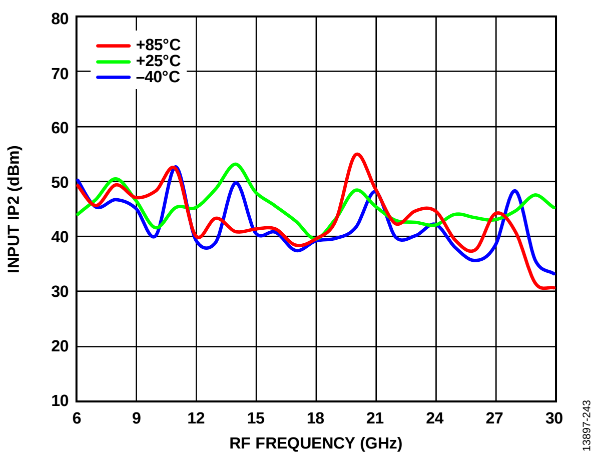

Figure 43. Input IP2 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

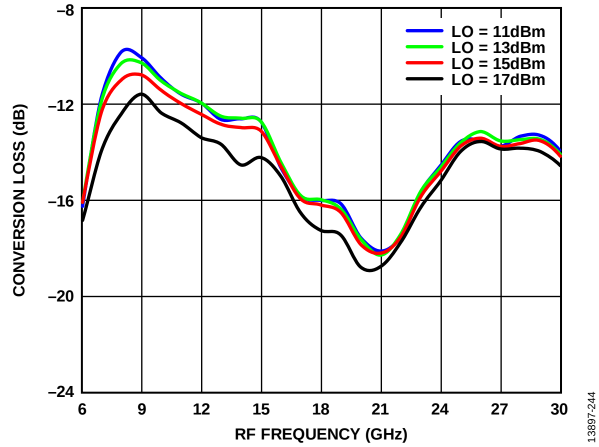

Figure 44. Conversion Loss vs. RF Frequency over Various LO Drives

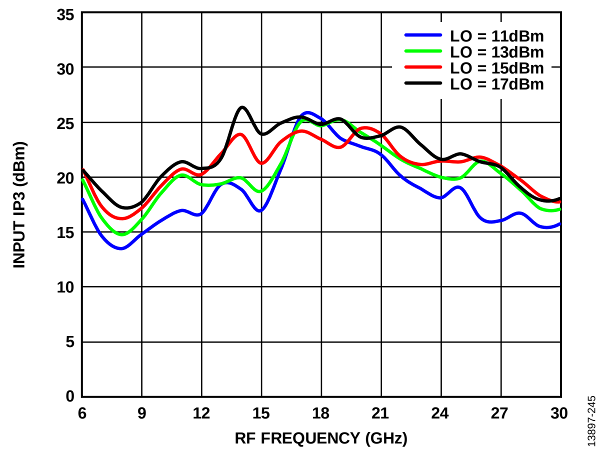

Figure 45. Input IP3 vs. RF Frequency over Various LO Drives

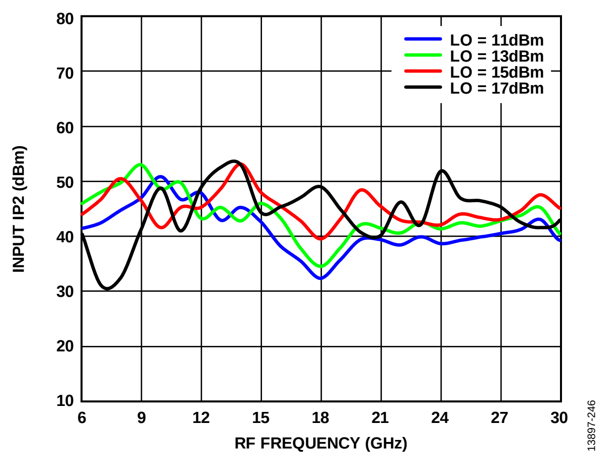

Figure 46. Input IP2 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 500 MHz, UPPER SIDEBAND

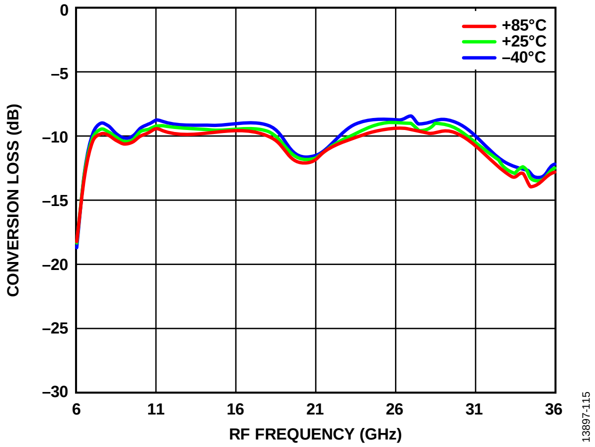

Figure 47. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

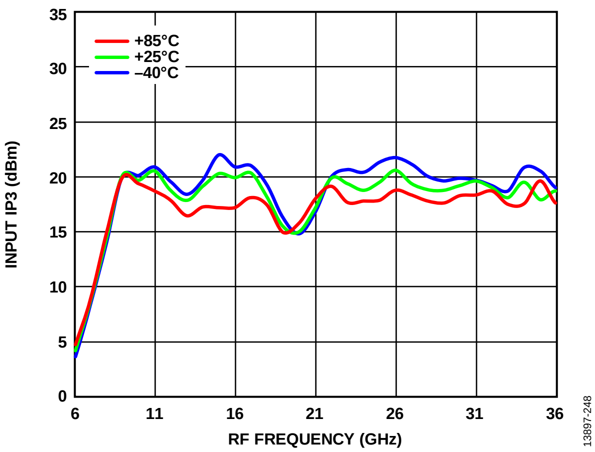

Figure 48. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

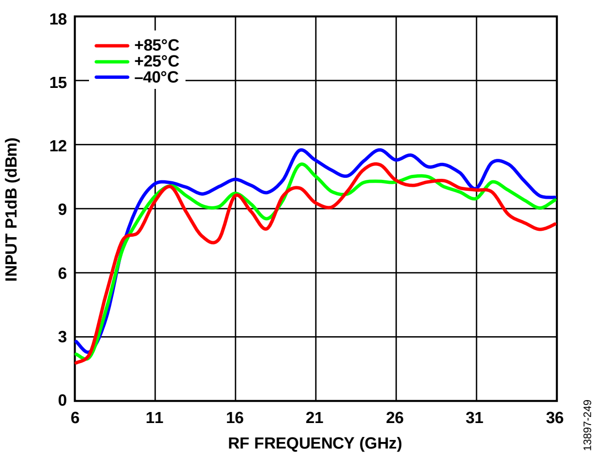

Figure 49. Input P1dB vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

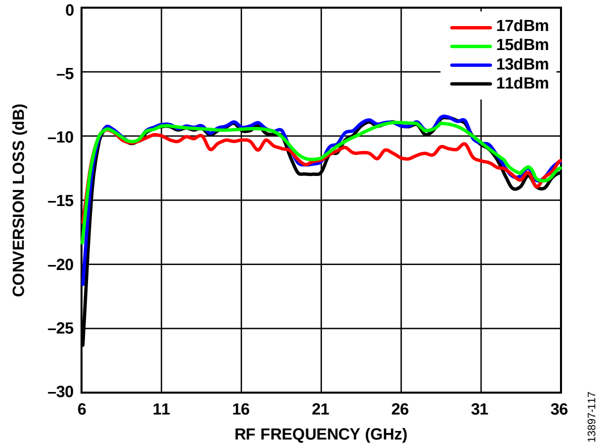

Figure 50. Conversion Loss vs. RF Frequency over LO Drives

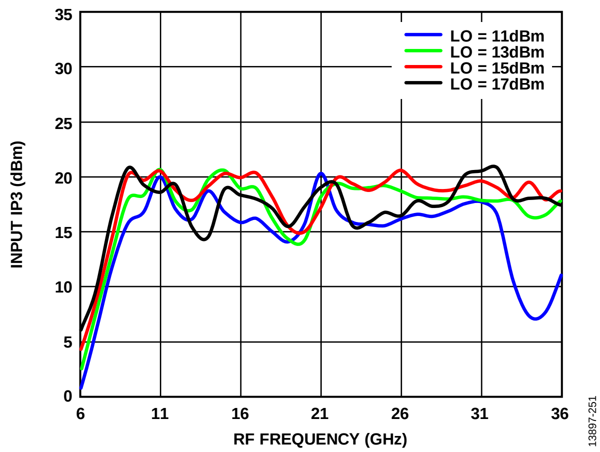

Figure 51. Input IP3 vs. RF Frequency over Various LO Drives

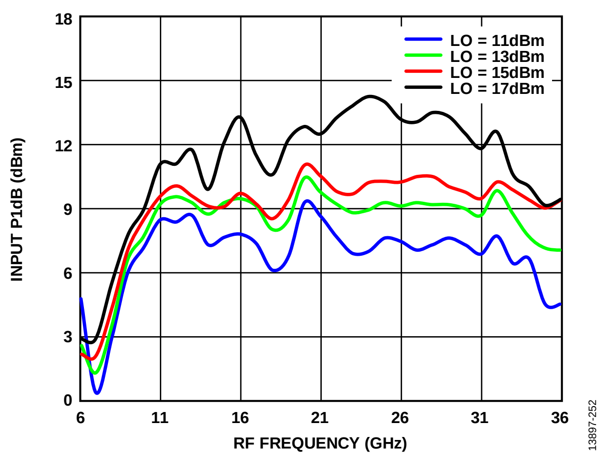

Figure 52. Input P1dB vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 500 MHz, LOWER SIDEBAND

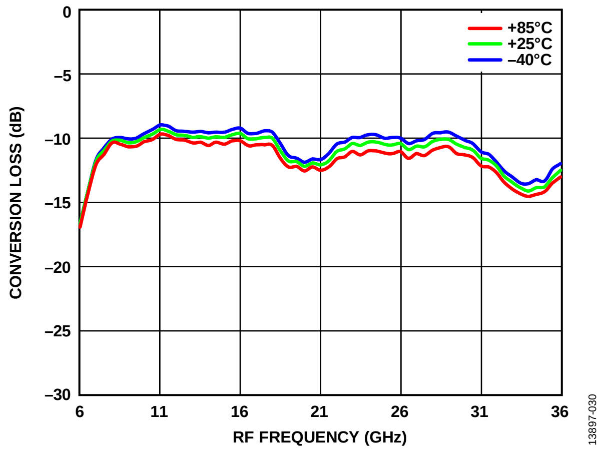

Figure 53. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

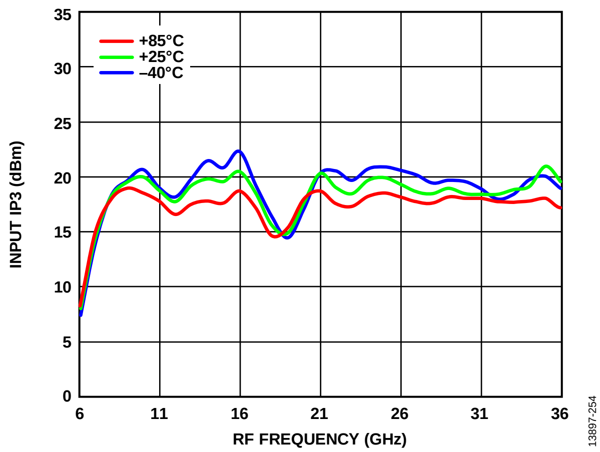

Figure 54. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

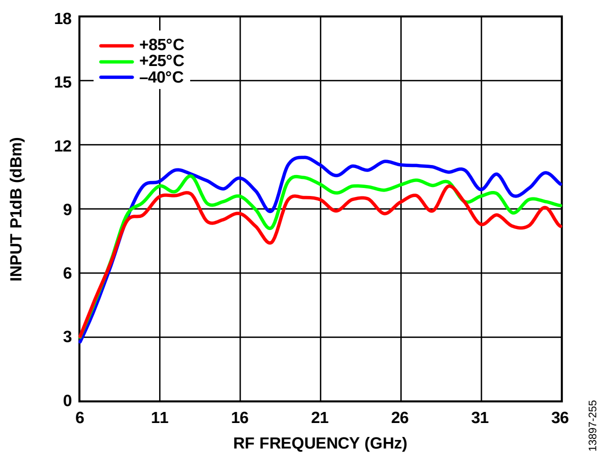

Figure 55. Input P1dB vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

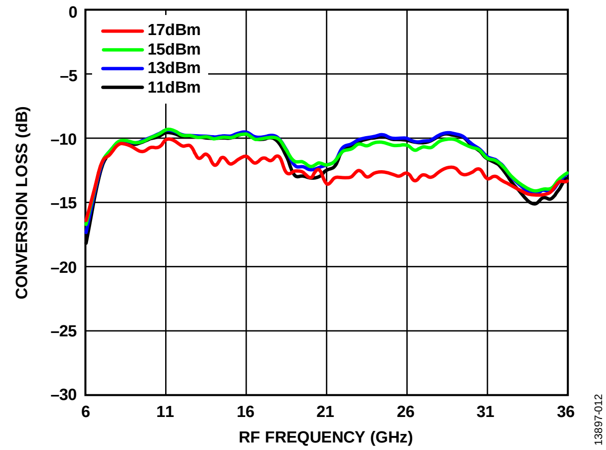

Figure 56. Conversion Loss vs. RF Frequency over LO Drives

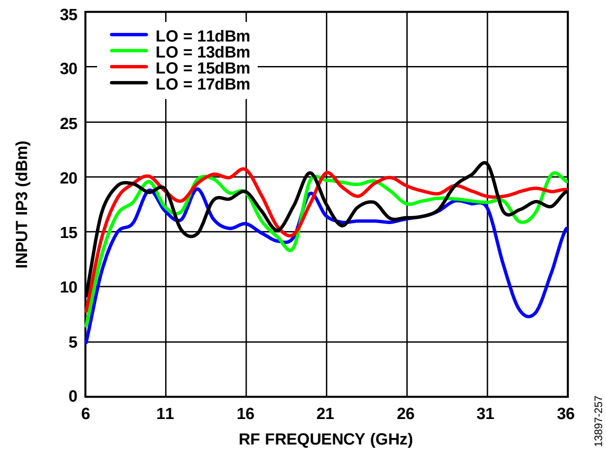

Figure 57. Input IP3 vs. RF Frequency over Various LO Drives

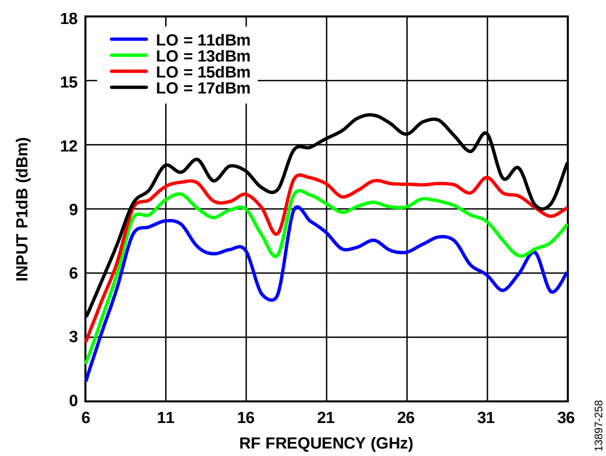

Figure 58. Input P1dB vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 3000 MHz, UPPER SIDEBAND

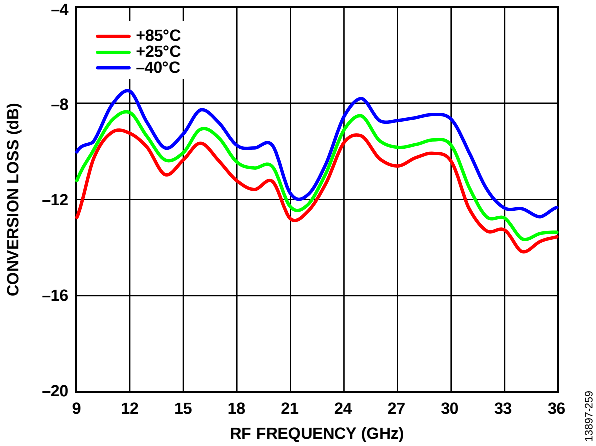

Figure 59. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

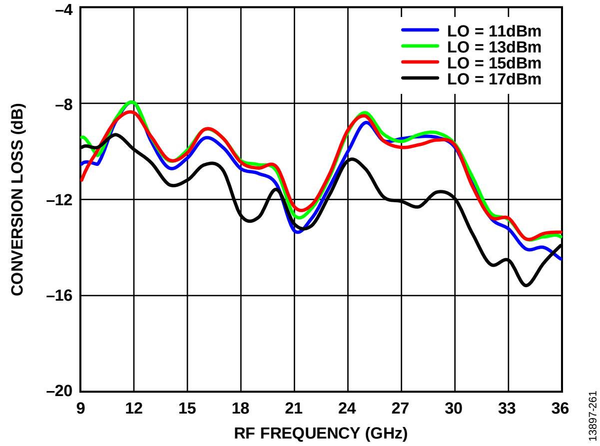

Figure 61. Conversion Loss vs. RF Frequency over LO Drives

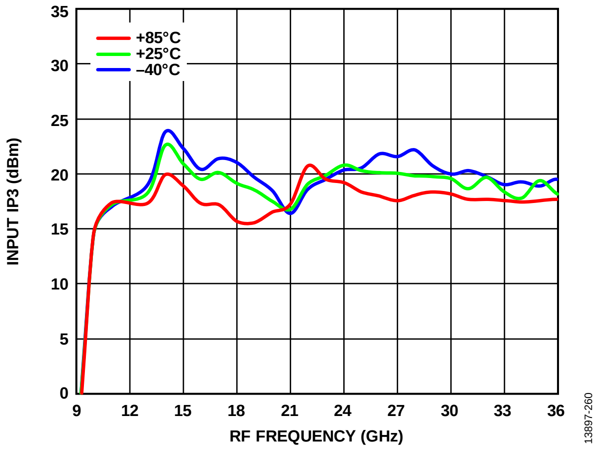

Figure 60. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

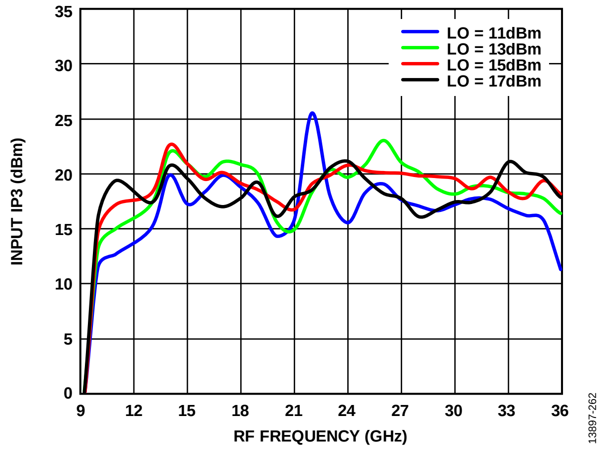

Figure 62. Input IP3 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 3000 MHz, LOWER SIDEBAND

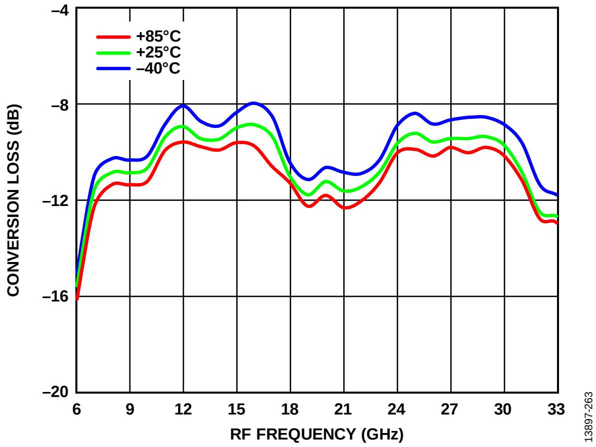

Figure 63. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

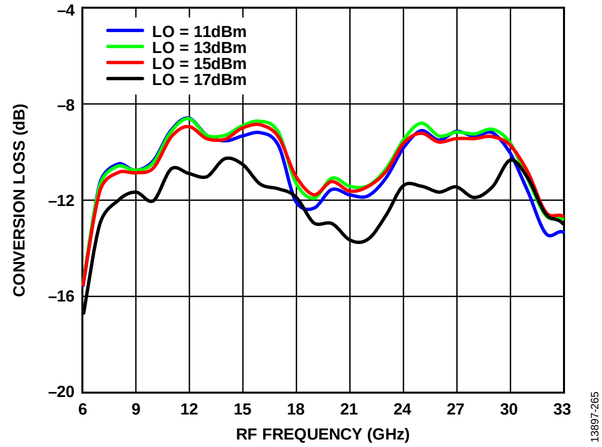

Figure 65. Conversion Loss vs. RF Frequency over LO Drives

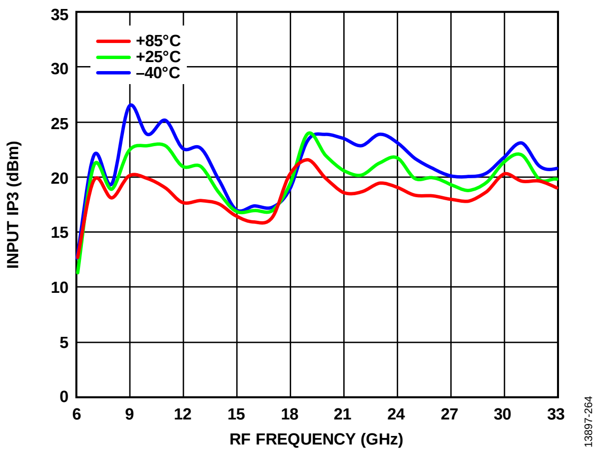

Figure 64. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

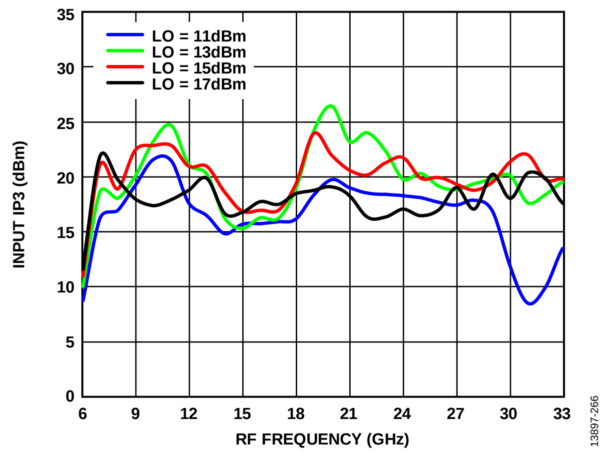

Figure 66. Input IP3 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 8000 MHz, UPPER SIDEBAND

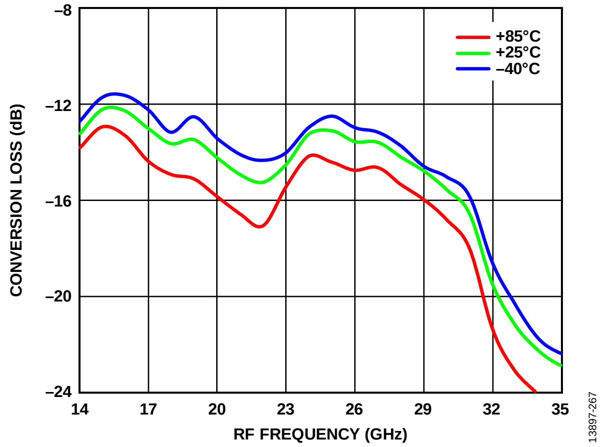

Figure 67. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

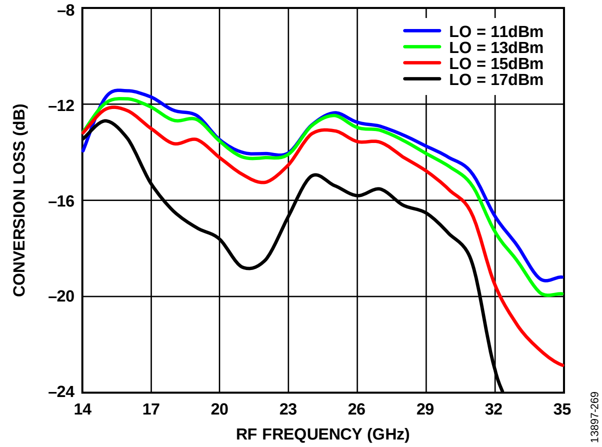

Figure 69. Conversion Loss vs. RF Frequency over LO Drives

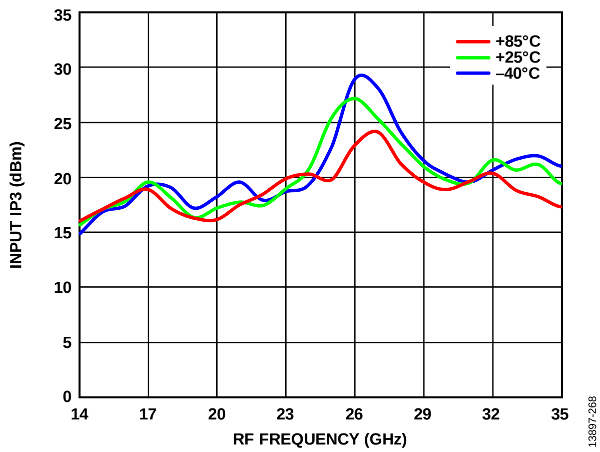

Figure 68. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

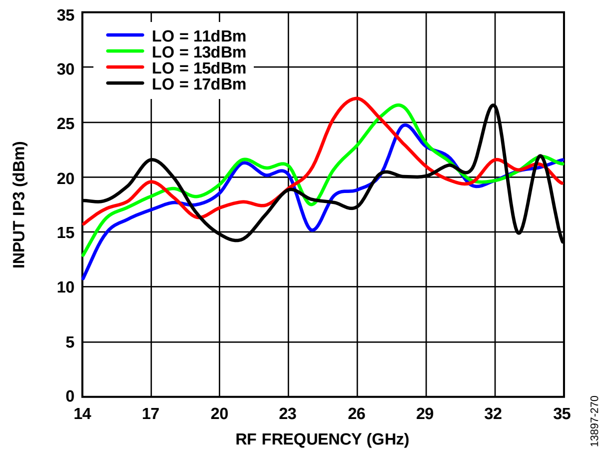

Figure 70. Input IP3 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 8000 MHz, LOWER SIDEBAND

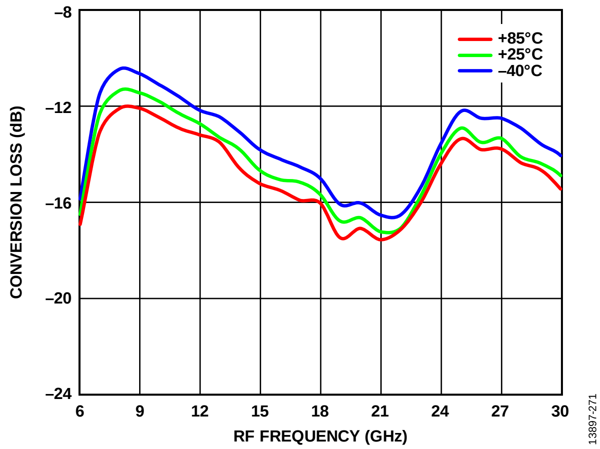

Figure 71. Conversion Loss vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

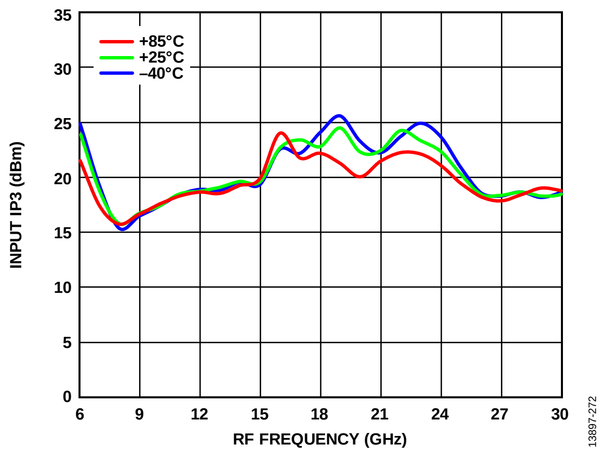

Figure 72. Input IP3 vs. RF Frequency over Various Temperatures, P_{LO} = 15 dBm

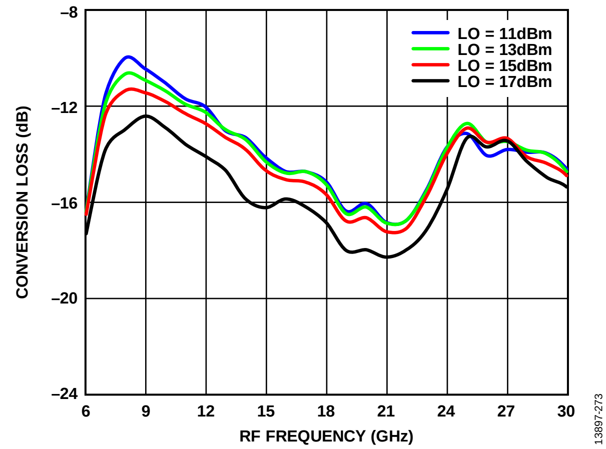

Figure 73. Conversion Loss vs. RF Frequency over LO Drives

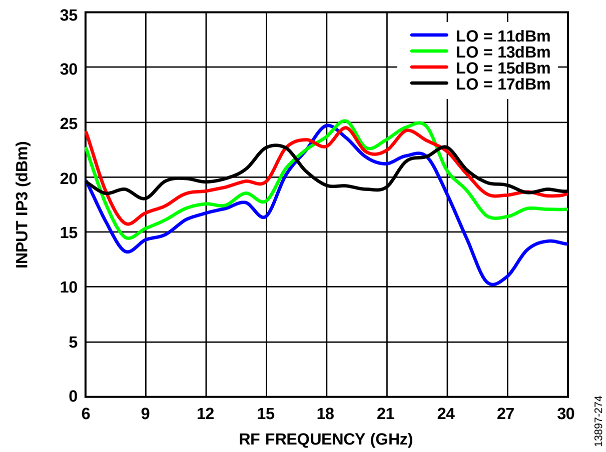

Figure 74. Input IP3 vs. RF Frequency over Various LO Drives

IF BANDWIDTH, LO = 28 GHz, UPPER SIDEBAND

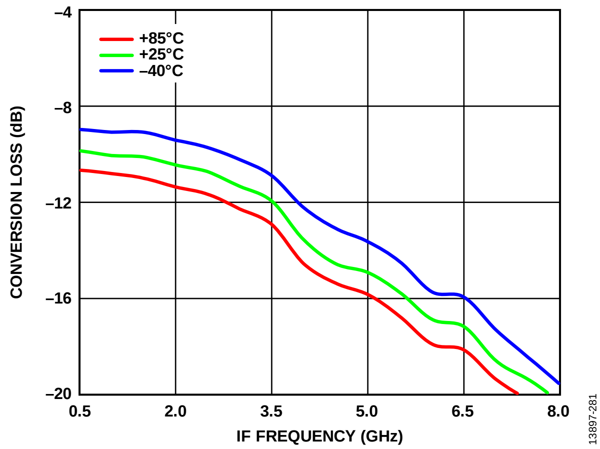

Figure 75. Conversion Loss vs. IF Frequency over Various Temperatures, P_{LO} = 15 dBm

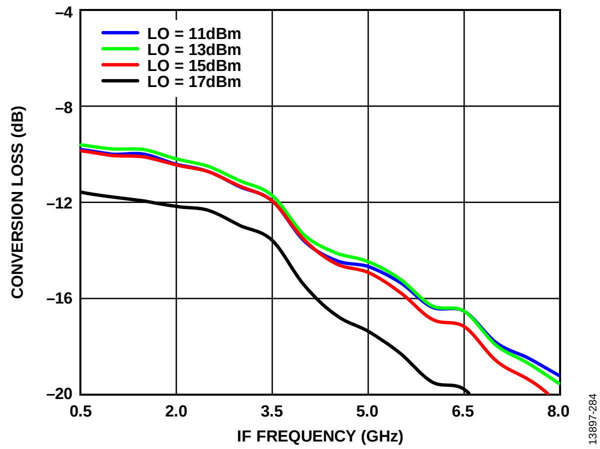

Figure 78. Conversion Loss vs. IF Frequency over Various LO Drives

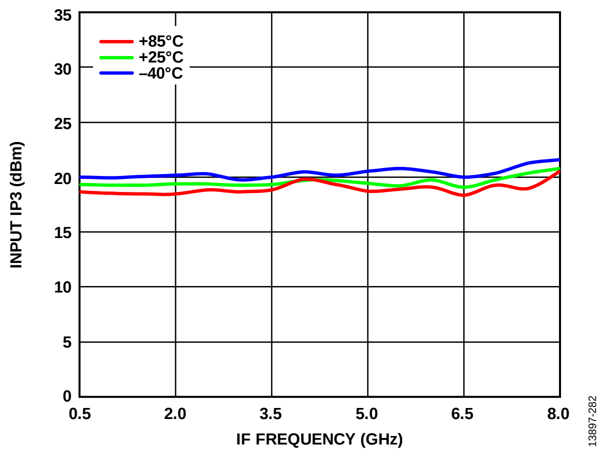

Figure 76. Input IP3 vs. IF Frequency over Various Temperatures, P_{LO} = 15 dBm

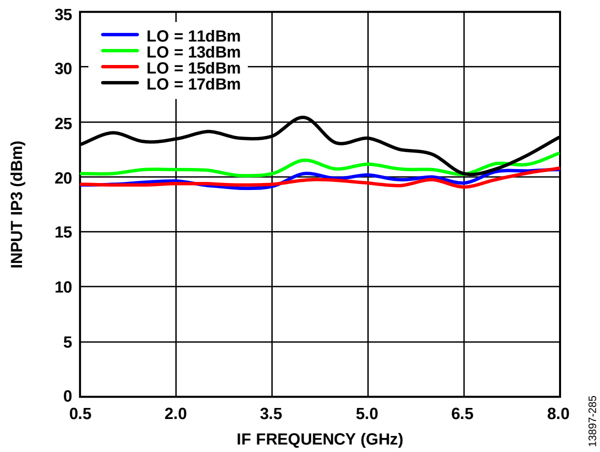

Figure 79. Input IP3 vs. IF Frequency over Various LO Drives

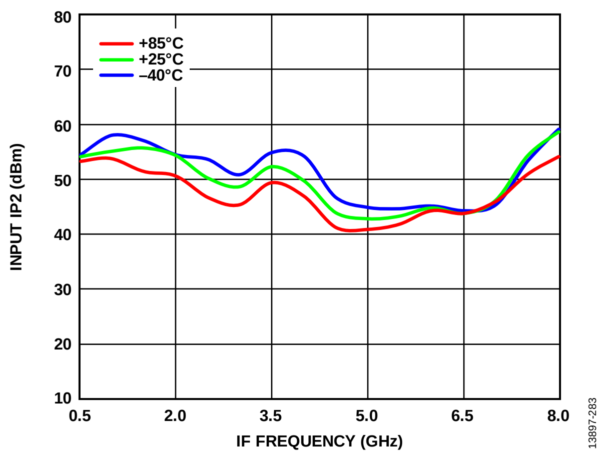

Figure 77. Input IP2 vs. IF Frequency over Various Temperatures, P_{LO} = 15 dBm

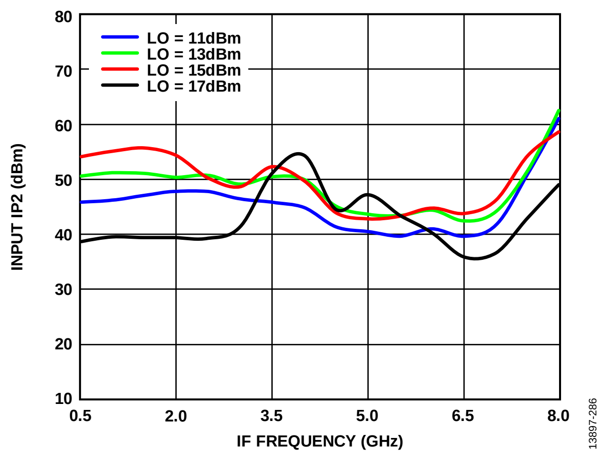

Figure 80. Input IP2 vs. IF Frequency over Various LO Drives

IF BANDWIDTH, LO = 34 GHz, LOWER SIDEBAND

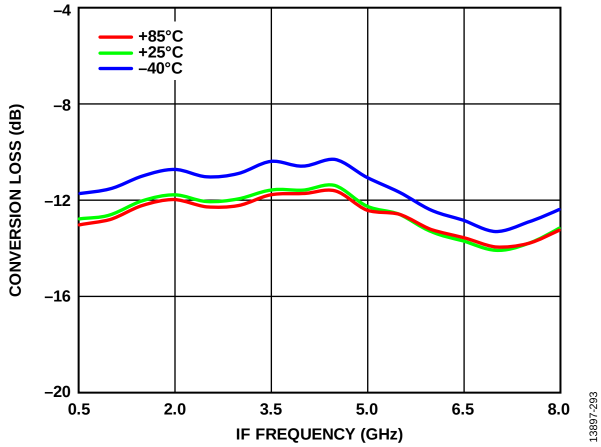

Figure 81. Conversion Loss vs. IF Frequency over Various Temperatures, P_{LO} = 15 dBm

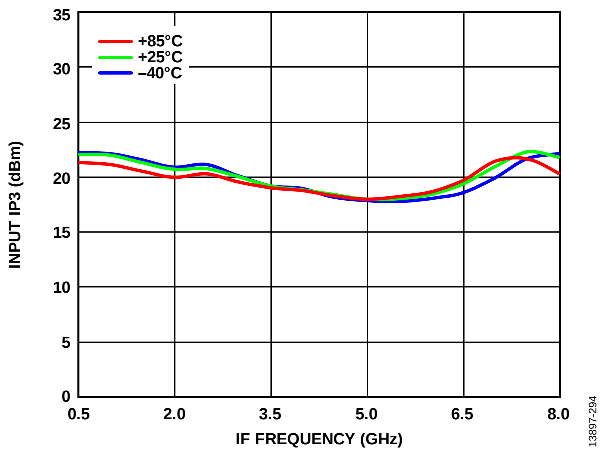

Figure 82. Input IP3 vs. IF Frequency over Various Temperatures, P_{LO} = 15 dBm

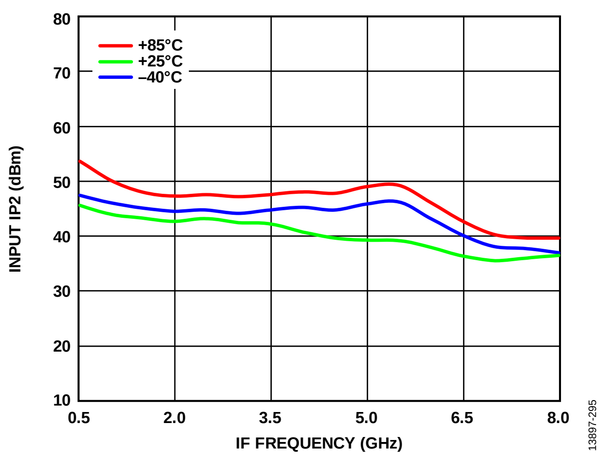

Figure 83. Input IP2 vs. IF Frequency over Various Temperatures, P_{LO} = 15 dBm

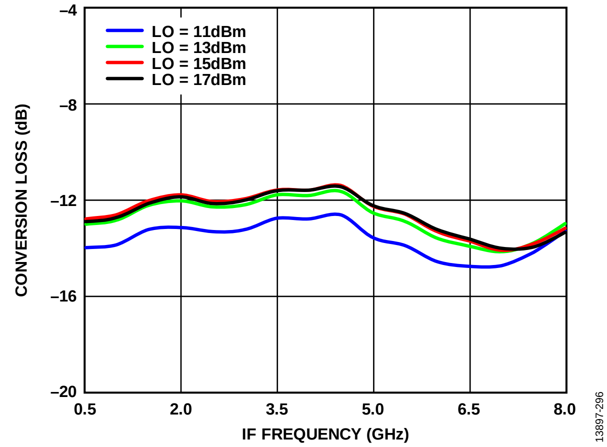

Figure 84. Conversion Loss vs. IF Frequency over Various LO Drives

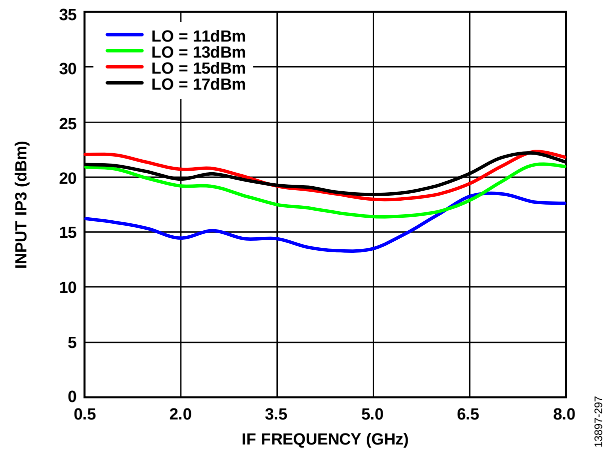

Figure 85. Input IP3 vs. IF Frequency over Various LO Drives

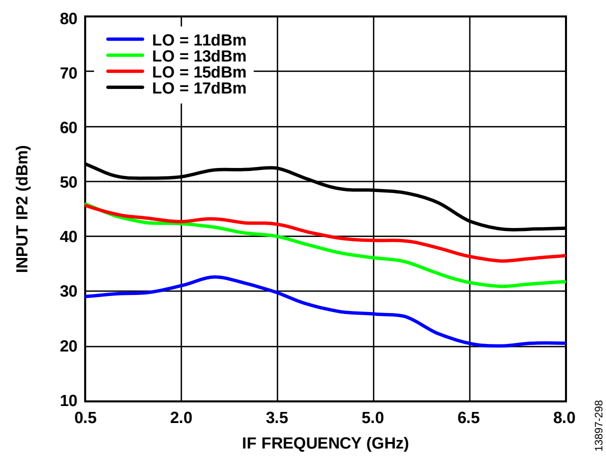

Figure 86. Input IP2 vs. IF Frequency over Various LO Drives

ISOLATION AND RETURN LOSS

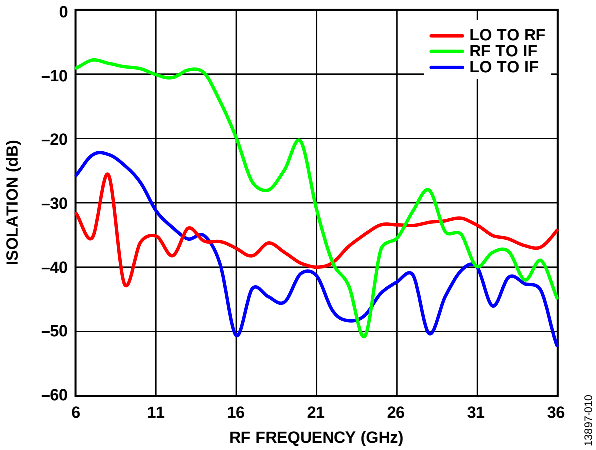

Figure 87. Isolation vs. RF Frequency for Various Isolations

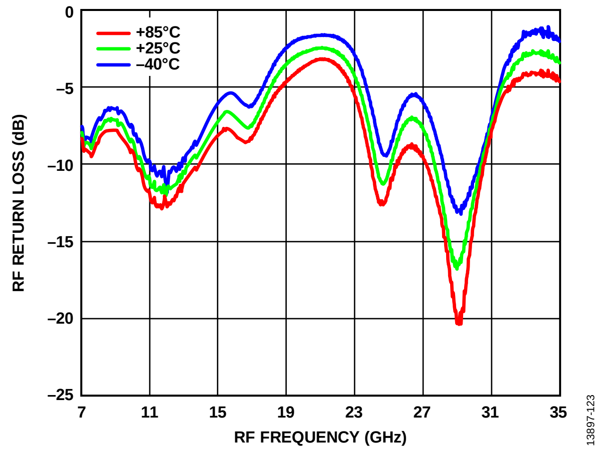

Figure 90. RF Return Loss vs. RF Frequency over Various Temperatures at f_{LO} = 7 GHz, P_{LO} = 15 dBm

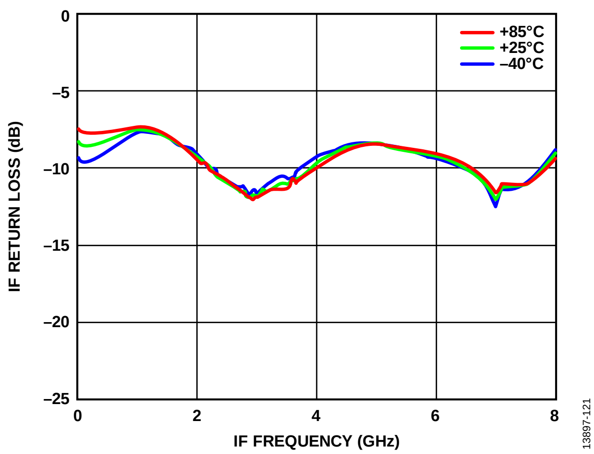

Figure 88. IF Return Loss vs. IF Frequency over Various Temperatures at f_{LO} = 7 GHz, P_{LO} = 15 dBm

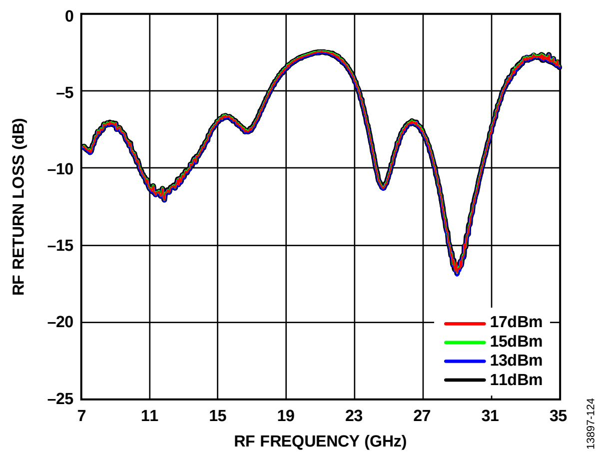

Figure 91. RF Return Loss vs. RF Frequency over Various LO Drives at f_{LO} = 7 GHz

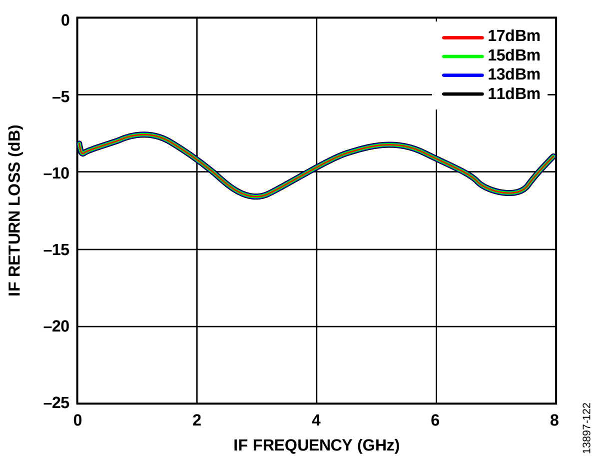

Figure 89. IF Return Loss vs. IF Frequency over Various LO Drives at f_{LO} = 7 GHz, T_A = 25°C

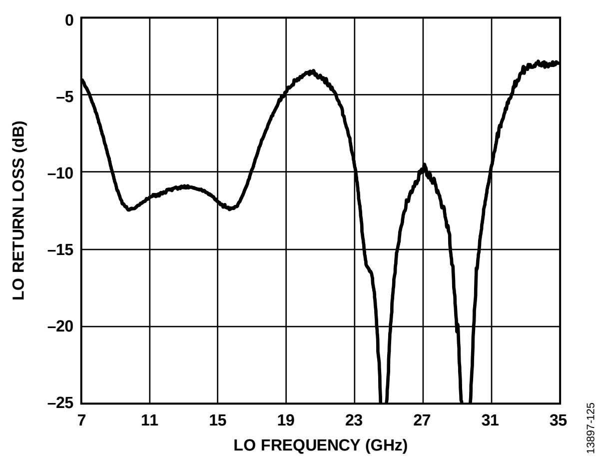

Figure 92. LO Return Loss vs. LO Frequency at T_A = 25°C, P_{LO} = 15 dBm

SPURIOUS PERFORMANCE

LO Harmonics

When measuring the LO harmonics, the 15 dBm LO input power is applied at various LO frequencies.

All values are in decibels below the LO power level measured at the RF port. N/A means not applicable.

Table 6. LO Frequency vs. N × LO Spur at RF Port

	N × LO Spur at RF Port			
LO Frequency (GHz)	**1**	**2**	**3**	**4**
8	33	29	50	46
10	41	34	69	47
18	36	59	N/A	N/A
28	32	N/A	N/A	N/A

All values are in decibels below the LO power level measured at the IF port. N/A means not applicable.

Table 7. LO Frequency vs. N × LO Spur at IF Port

	N × LO Spur at IF Port			
LO Frequency (GHz)	**1**	**2**	**3**	**4**
8	49	73	97	113
10	55	80	100	118
18	68	110	N/A	N/A
28	65	N/A	N/A	N/A

M × N Spurious Outputs

Mixer spurious products are measured in decibels from either below the RF or the IF output power level. N/A means not applicable.

RF = 17.5 GHz at −10 dBm, and LO = 18 GHz at +15 dBm are applied. Spur values are (M × RF) − (N × LO).

		N × LO				
		0	**1**	**2**	**3**	**4**
M × RF	**0**	N/A	13	40	N/A	N/A
	1	18	0	54	50	N/A
	2	62	74	63	72	63
	3	N/A	66	75	71	74
	4	N/A	N/A	63	74	86

IF = 0.5 GHz at −10 dBm, and LO = 18 GHz at +15 dBm are applied. Spur values are (M × IF) + (N × LO).

		N × LO				
		0	**1**	**2**	**3**	**4**
M × IF	**−4**	86	79	66	N/A	N/A
	−3	88	59	65	N/A	N/A
	−2	67	39	62	N/A	N/A
	−1	38	0	21	N/A	N/A
	0	N/A	2	26	N/A	N/A
	+1	38	0	18	N/A	N/A
	+2	67	40	53	N/A	N/A
	+3	84	65	60	N/A	N/A
	+4	87	77	60	N/A	N/A

THEORY OF OPERATION

The HMC774ALC3B is a general-purpose, double balanced mixer that can be used as an upconverter or a downconverter from 7 GHz to 34 GHz.

When used as a downconverter, the HMC774ALC3B down-converts RF between 7 GHz and 34 GHz to IF between dc and 8 GHz.

When used as an upconverter, the HMC774ALC3B upconverts IF between dc and 8 GHz to RF between 7 GHz and 34 GHz.

APPLICATIONS INFORMATION

EVALUATION BOARD

Figure 93 and Figure 94 show the top and cross sectional views of the evaluation board, which uses 4-layer construction, with a copper thickness of 0.5 oz (0.7 mil) and dielectric materials between each copper layer.

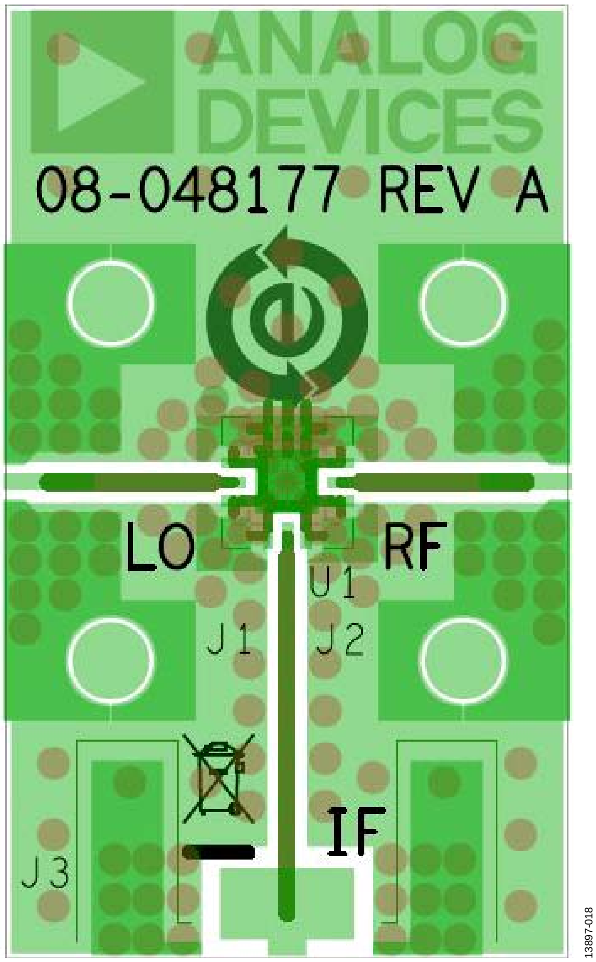

Figure 93. Evaluation Board Layout Top View

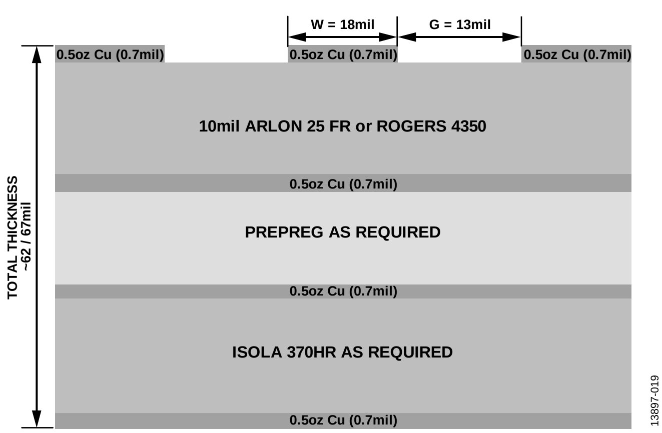

Figure 94. Evaluation Board Cross Sectional View

All RF traces are routed on Layer 1, and all other remaining layers are ground planes that provide a solid ground for RF transmission lines. The top dielectric material is Rogers 4350, offering low loss performance. The prepreg material in the middle sticks core layers together, which includes an Isola 370HR layer with copper traces above and below. Both the prepreg material and the Isola 370HR core layer are used to achieve required board finish thickness.

The RF transmission lines are designed using a coplanar waveguide (CPWG) model with a width of 18 mil and ground spacing of 13 mil for a characteristic impedance of 50 Ω. For optimal RF and thermal grounding, as many plated through vias as possible are arranged around the transmission lines and under the exposed pad of the package.

Figure 95 shows the actual EV1HMC774ALC3B evaluation board with component placement. Because the EV1HMC774ALC3B is a passive device, there is no requirement for external components. The LO, RF, and IF pins are internally dc-coupled. Use an external series capacitor when an operation is not required. Choose a value that stays within the necessary frequency range for each port. When an operation to dc is required, do not exceed the source and sink current ratings specified in the Absolute Maximum Ratings section.

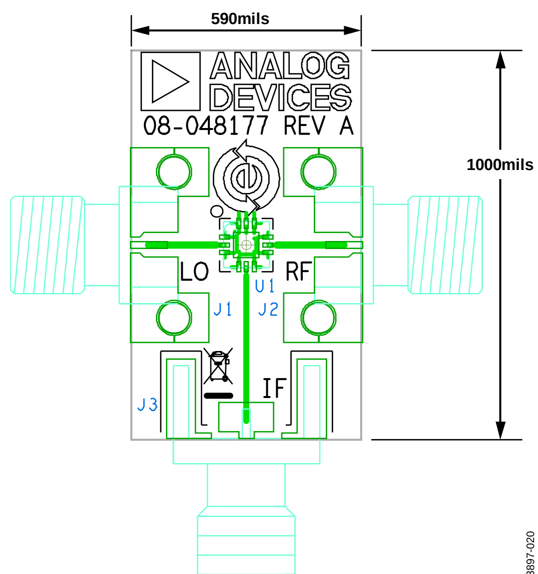

Figure 95. EV1HMC774ALC3B Evaluation Board

The EV1HMC774ALC3B evaluation board shown in Figure 95 is available for order from the Analog Devices, Inc., website at www.analog.com.

Figure 96 shows the Pb-free reflow solder profile.

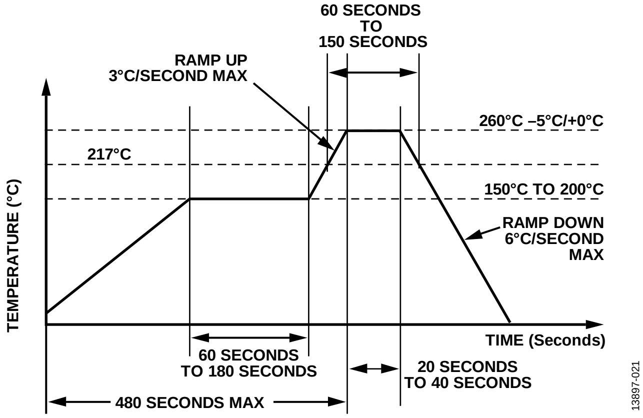

Figure 96. Pb-Free Reflow Solder Profile

Figure 97 shows the evaluation board schematic, and Table 8 lists the bill of materials for the EV1HMC774ALC3B evaluation board shown in Figure 95.

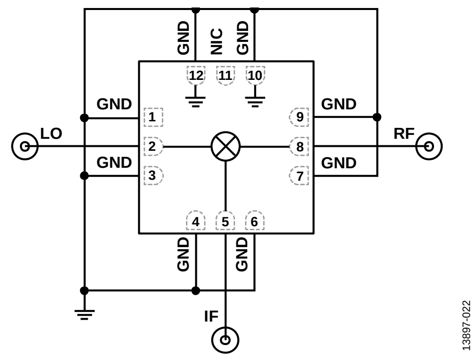

Figure 97. EV1HMC774ALC3B Evaluation Board Schematic

Table 8. Bill of Materials for the EV1HMC774ALC3B Evaluation Board

Component	Description
J1, J2	2.92 mm connector
J3	SMA connector
U1	HMC774ALC3B
PCB[1]	08-048177 Evaluation PCB

[1] 108-047919 is the raw bare PCB identifier. Reference the EV1HMC774ALC3B part number when ordering the complete evaluation PCB.

OUTLINE DIMENSIONS

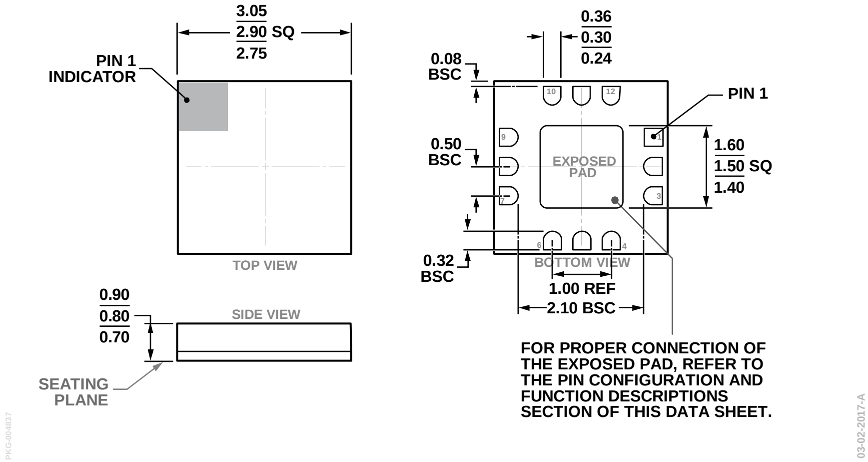

Figure 98. 12-Terminal Ceramic Leadless Chip Carrier [LCC]
(E-12-4)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Moisture Sensitivity Level (MSL) Rating[2]	Package Description	Package Option
HMC774ALC3B	−40°C to +85°C	MSL3	12-Terminal Ceramic Leadless Chip Carrier [LCC]	E-12-4
HMC774ALC3BTR	−40°C to +85°C	MSL3	12-Terminal Ceramic Leadless Chip Carrier [LCC]	E-12-4
HMC774ALC3BTR-R5	−40°C to +85°C	MSL3	12-Terminal Ceramic Leadless Chip Carrier [LCC]	E-12-4
EV1HMC774ALC3B			Evaluation PCB Assembly	

[1] All models are RoHS Compliant Parts.
[2] See Figure 96 for the peak reflow temperature.

D13897-0-6/18(A)

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